

ST2060C STB2060C

Technical Data Data Sheet N1421, Rev. A

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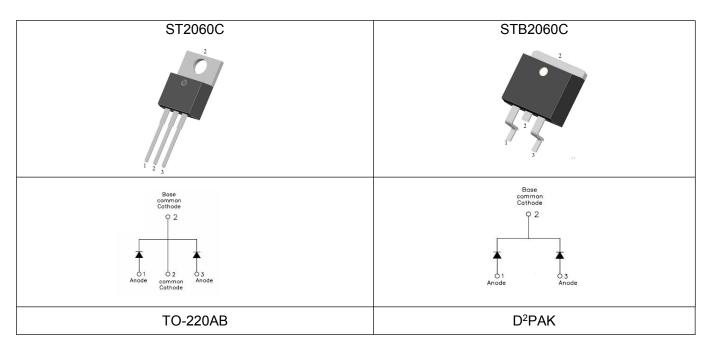
ST2060C/STB2060C SCHOTTKY RECTIFIER

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Features

- 150 °C T_J operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Trench MOS Schottky technology
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage	V _{RRM}	-		
Working Peak Reverse Voltage	VRWM		60	V
DC Blocking Voltage	V _R			
Average Destified Ferryard Current		50% duty cycle @Tc=105°C,	10(Per Leg)	^
Average Rectified Forward Current	IF (AV)	rectangular wave form	20(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	150	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 5A, Pulse, T」= 25℃ @ 10A, Pulse, T」= 25℃	0.41 0.50	- 0.65	V
	V _{F2}	@ 5A, Pulse, T」=125℃ @ 10A, Pulse, T」= 125℃	0.32 0.45	- 0.59	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = rated V_R$ T _J = 25°C	0.02	0.85	mA
	I _{R2}	@V _R = rated V _R T _J = 125℃	12	40	mA
Junction Capacitance	CT	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	700	-	pF

* Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

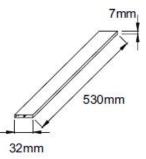
Characteristics	Symbol	ST2060C	STB2060C	Units
Junction Temperature	TJ	-55 to +150		°C
Storage Temperature	T _{stg}	-55 to +150		°C
Typical Thermal Resistance Junction to Case(Per Leg)	R _{θJC}	3.0	3.2	°C/W

Tube Specification

Device	Package	Weight	Shipping
ST2060C	TO-220AB	2.0	50pcs / tube
STB2060C	D ² PAK	1.85	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification(TO-220AB)



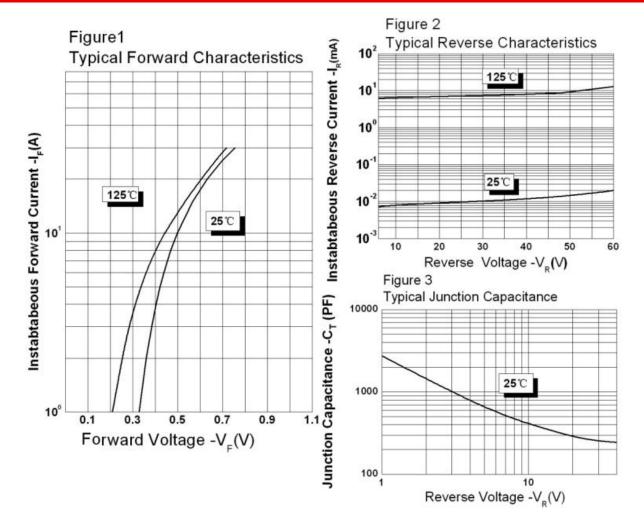


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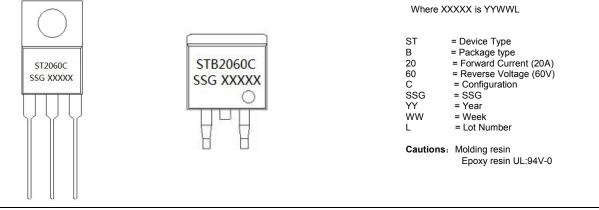
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Ratings and Characteristics Curves



Marking Diagram



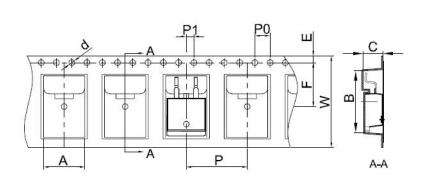
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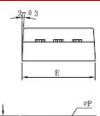
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Carrier Tape Specification D2PAK



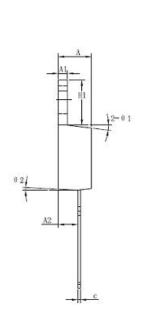
SYMBOL	Millimeters		
STMBOL	Min.	Max.	
A	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

Mechanical Dimensions TO-220AB



D1

3-b1



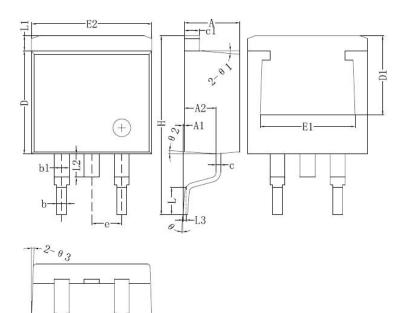
Symbol	Dimensions in millimeters			
	Min	Typical	Max	
A	4.42	4.57	4.72	
A1	1.17	1.27	1.37	
A2	2.52	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
E	10.01	10.16	10.31	
е		2.54		
e1	4.98	5.06	5.18	
H1	6.04	6.24	6.44	
L	12.7	13.56	13.80	
L1	3.56	3.5	3.96	
ΦΡ	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7°		
Θ2		3°		
Θ3		4°		



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Mechanical Dimensions D²PAK



Symbol	Dimensions in millimeters				
	Min.	Typical	Max.		
A	4.47	4.70	4.85		
A1	0	0.10	0.25		
A2	2.59	2.69	2.89		
b	0.71	0.81	0.96		
b1	1.17	1.27	1.37		
С	0.31	0.38	0.61		
c1	1.17	1.27	1.37		
D	8.50	8.70	8.90		
D1	6.40				
E	10.01	10.16	10.31		
E1	7.6				
E2	9.98	10.08	10.31		
е		2.54			
Н	14.6	15.1	15.6		
L	2.00	2.30	2.74		
L1	1.12	1.27	1.42		
L2	1.30		2.20		
L3		0.25BSC			
е	0	-	8°		
e1		5°			
e2		4°			
e3		4°			

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